

Title (en)
MGO-BASE COATING FOR ELECTRICALLY INSULATING SEMI-CONDUCTOR SUBSTRATES AND PRODUCTION METHOD

Title (de)
MGO-BASIERTE BESCHICHTUNG FÜR ELEKTRISCH ISOLIERENDE HALBLEITERSUBSTRATE UND HERSTELLUNGSVERFAHREN DAFÜR

Title (fr)
REVETEMENT A BASE DE MGO POUR L'ISOLATION ELECTRIQUE DE SUBSTRATS SEMI-CONDUCTEURS ET PROCEDE DE FABRICATION

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Application
EP 05810812 A 20051012

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Abstract (en)
[origin: WO2006040499A1] The invention relates to an inorganic magnesium oxide-based coating (MgO) for electrically insulating semi-conductor substrates such as a silicon carbide (SiC) and to a method for producing said insulating coating. The inventive method consists in preparing a treating solution of at least one type of water-soluble organomagnesium and/or of at least one type of a water-soluble magnesium salt for forming a homogenous polymer magnesium oxide/hydroxide layer by a hydrolysis-condensation reaction with water, in applying the treating water-soluble organomagnesium or water-soluble magnesium salt solution to a surface for forming a magnesium oxide-base layer and in densifying the thus formed layer at a temperature equal to or less than 1000 °C.

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H01L 21/316 (2006.01)

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C-Set (source: EP US)
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Citation (examination)
US 6071555 A 20000606 - SENGUPTA SOMNATH [US], et al

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